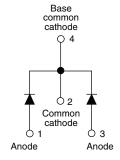


Vishay Semiconductors

Schottky Rectifier, 2 x 3.5 A





D-PAK ((TO-252AA)
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PRODUCT SUMMARY	
Package	D-PAK (TO-252AA)
I _{F(AV)}	2 x 3.5 A
V_R	40 V
V _F at I _F	See Electrical table
I _{RM}	24 mA at 125 °C
T _J max.	150 °C
Diode variation	Common cathode
E _{AS}	8 mJ

FEATURES

- Popular D-PAK outline
- Center tap configuration



- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- \bullet Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

DESCRIPTION

The VS-6CWQ04FNPbF surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	CHARACTERISTICS	VALUES	UNITS							
I _{F(AV)}	Rectangular waveform	7	А							
V _{RRM}		40	V							
I _{FSM}	t _p = 5 μs sine	500	Α							
V _F	3 Apk, T _J = 125 °C (per leg)	0.49	V							
TJ	Range	- 40 to 150	°C							

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-6CWQ04FNPbF	UNITS						
Maximum DC reverse voltage	V_{R}	40	V						
Maximum working peak reverse voltage	V_{RWM}	40							

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS					
Maximum average per leg		50 % duty cycle at T _C = 135 °C	3.5	A					
See fig. 5 per device	I _{F(AV)}	30 % duty cycle at 16 = 103 °C	7						
Maximum peak one cycle non-repetitive surge current per leg	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	500					
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	80					
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1 \text{A}, L = 16 \text{mH}$		8.0	mJ				
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zer Frequency limited by T_J maxim	1.0	А					

VS-6CWQ04FNPbF

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS						
	V (1)	3 A	- T _{.I} = 25 °C	0.53	V				
Maximum forward voltage drop per leg		6 A	11 = 23 0	0.67					
See fig. 1	V _{FM} ⁽¹⁾	3 A	T _{.1} = 125 °C	0.49					
		6 A	1j = 125 C	0.62					
Maximum reverse leakage	I _{RM} ⁽¹⁾	T _J = 25 °C	- V _B = Rated V _B	2	- mA				
current per leg See fig. 2		T _J = 125 °C	v _R = nateu v _R	24					
Threshold voltage	$V_{F(TO)}$	T - T maximum		0.34	V				
Forward slope resistance	r _t	$T_J = T_J$ maximum		37.33	m $Ω$				
Typical junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal range 1	189	pF					
Typical series inductance per leg	L _S	Measured lead to lead 5 mm f	5.0	nΗ					
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs				

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C			
Maximum thermal resistance,	per leg	D	DC operation	4.70	°C/W			
junction to case	per device	R_{thJC}	See fig. 4	2.35				
Approximate weight				0.3	g			
Approximate weight				0.01	OZ.			
Marking device			Case style D-PAK (similar to TO-252AA)	6CWQ	04FN			

Note

$$\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$$
 thermal runaway condition for a diode on its own heatsink



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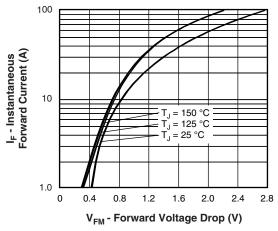


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

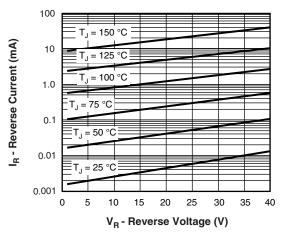


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

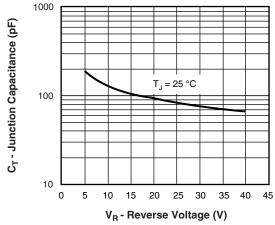


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

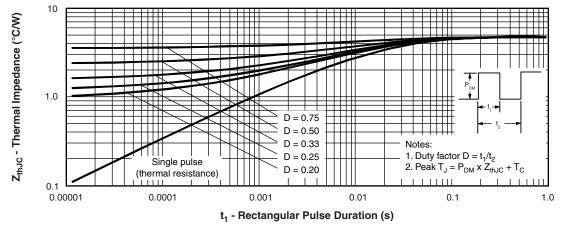
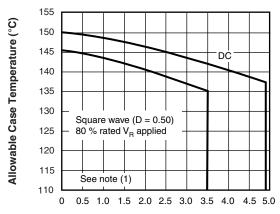


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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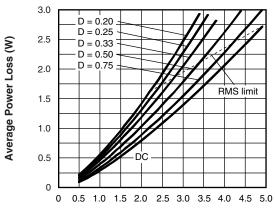
Schottky Rectifier, 2 x 3.5 A





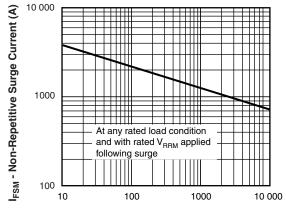
I_{F(AV)} - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)



I_{F(AV)} - Average Forward Current (A)

Fig. 6 - Forward Power Loss Characteristics (Per Leg)



t_o - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

 $\begin{array}{ll} \text{(1)} \ \ \text{Formula used:} \ T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at} \ (I_{F(AV)}/D) \ \text{(see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \ \text{(1 - D)}; \ I_R \ \text{at} \ V_{R1} = 80 \ \% \ \text{rated} \ V_R \end{aligned}$

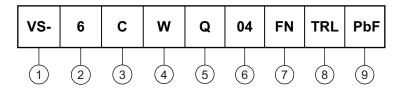


Schottky Rectifier, 2 x 3.5 A

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ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (7 A)
- 3 Center tap configuration
- 4 Package identifier:
 - W = D-PAK
- 5 Schottky "Q" series
- 6 Voltage rating (04 = 40 V)
- 7 FN = TO-252AA (D-PAK)
- 8 • None = Tube (50 pieces)
 - TR = Tape and reel
 - TRL = Tape and reel (left oriented)
 - TRR = Tape and reel (right oriented)
- 9 PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95016					
Part marking information	www.vishay.com/doc?95059					
Packaging information	www.vishay.com/doc?95033					



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NOTES

3

2

MAX.

0.410

0.070

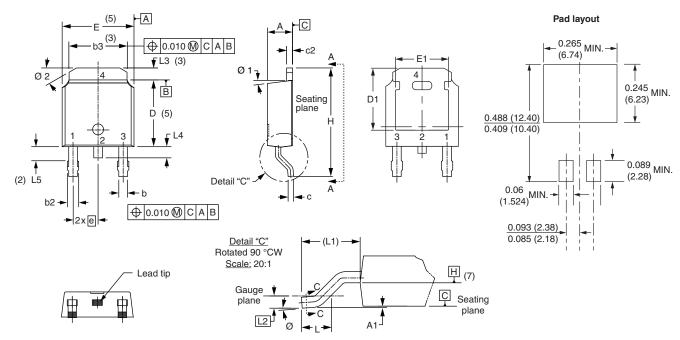
0.050

0.040

0.060

D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



Ī	SYMBOL	MILLIMETERS		INCHES		NOTES	CVMDOL	MILLIMETERS		INCHES		
	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX
ſ	Α	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC
ſ	A1	-	0.13		0.005			Н	9.40	10.41	0.370	0.41
Ī	b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.07
Ī	b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.
ſ	b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC
Ī	С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.05
Ī	c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.04
ſ	D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.06
Ī	D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°
ſ	Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°
Ī	E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- Lead dimension uncontrolled in L5
- Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- Outline conforms to JEDEC outline TO-252AA



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